2SC4050

Silicon NPN Epitaxial

HITACHI

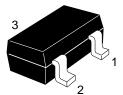
ADE-208-1095 (Z) 1st. Edition Mar. 2001

Application

Low frequency amplifier, switching

Outline

MPAK



- 1. Emitter
- 2. Base
- 3. Collector



2SC4050

Absolute Maximum Ratings $(Ta = 25^{\circ}C)$

| Item | Symbol | Ratings | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage | V_{CBO} | 120 | V |
| Collector to emitter voltage | V _{CEO} | 120 | V |
| Emitter to base voltage | V_{EBO} | 5 | V |
| Collector current | I _c | 100 | mA |
| Collector power dissipation | P _c | 150 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

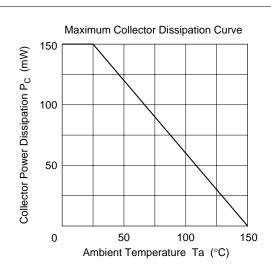
Electrical Characteristics ($Ta = 25^{\circ}C$)

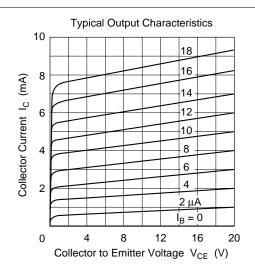
| Item | Symbol | Min | Тур | Max | Unit | Test conditions |
|---|----------------------|-----|-----|-----|------|--|
| Collector to base breakdown voltage | $V_{\text{(BR)CBO}}$ | 120 | _ | _ | V | $I_{c} = 10 \ \mu A, \ I_{E} = 0$ |
| Collector to emitter breakdown voltage | $V_{\text{(BR)CEO}}$ | 120 | _ | _ | V | $I_{C} = 1 \text{ mA}, R_{BE} = \infty$ |
| Emitter to base breakdown voltage | $V_{(BR)EBO}$ | 5 | _ | _ | V | $I_E = 10 \mu A, I_C = 0$ |
| Collector cutoff current | I _{CBO} | _ | _ | 0.1 | μΑ | $V_{CB} = 70 \text{ V}, I_{E} = 0$ |
| Emitter cutoff current | I _{EBO} | _ | _ | 0.1 | μΑ | $V_{EB} = 2 \text{ V}, I_{C} = 0$ |
| DC current transfer ratio | h _{FE} *1 | 250 | _ | 800 | | $V_{CE} = 12 \text{ V}, I_{C} = 2 \text{ mA}^{*2}$ |
| Collector to emitter saturation voltage | $V_{\text{CE(sat)}}$ | _ | _ | 0.1 | V | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA*}^2$ |
| Base to emitter saturation voltage | $V_{BE(sat)}$ | _ | _ | 1.1 | V | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA}^{*2}$ |

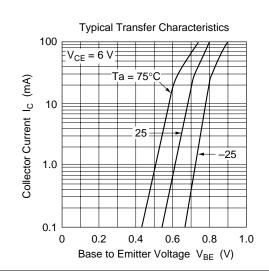
Notes: 1. The 2SC4050 is grouped by h_{FE} as follows.

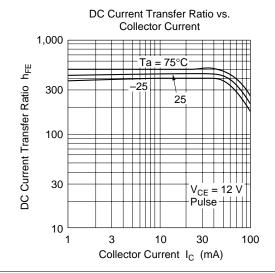
2. Pluse test

| Grade | D | E |
|-----------------|------------|------------|
| Mark | KID | KIE |
| h _{FE} | 250 to 500 | 400 to 800 |

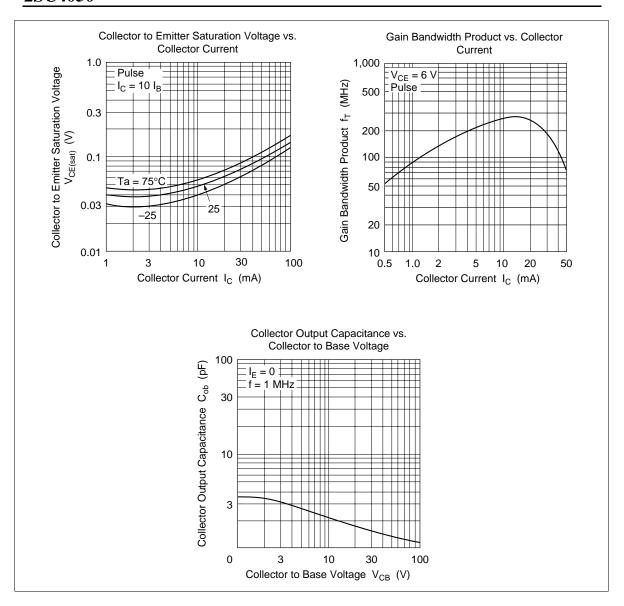




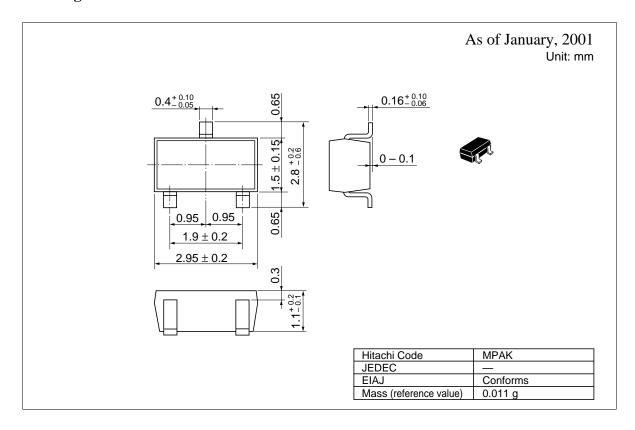




2SC4050



Package Dimensions



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